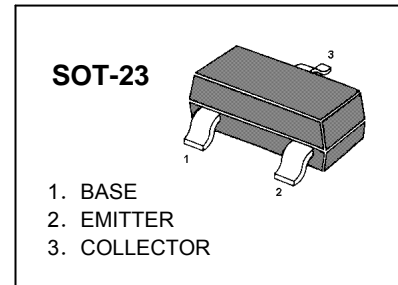


## BC817 TRANSISTOR(NPN)

### FEATURE

- ◆ For general AF applications
- ◆ High collector current
- ◆ High current gain
- ◆ Low collector-emitter saturation voltage
- ◆ Complementary types: BC807 (PNP)



### MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	45	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	0.5	A
$P_C$	Collector Power Dissipation	0.3	W
$T_j$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^{\circ}\text{C}$

### ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{CBO}$	$I_C = 10\mu\text{A}, I_E = 0$	50			V
Collector-emitter breakdown voltage	$V_{CEO}$	$I_C = 10\text{mA}, I_B = 0$	45			V
Emitter-base breakdown voltage	$V_{EBO}$	$I_E = 1\mu\text{A}, I_C = 0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = 45\text{V}, I_E = 0$			0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 4\text{V}, I_C = 0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE(1)}$	$V_{CE} = 1\text{V}, I_C = 100\text{mA}$	100		600	
	$h_{FE(2)}$	$V_{CE} = 1\text{V}, I_C = 500\text{mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$			0.7	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$			1.2	V
Base-emitter voltage	$V_{BE}$	$V_{CE} = 1\text{V}, I_C = 500\text{mA}$			1.2	V
Collector capacitance	$C_{ob}$	$V_{CB} = 10\text{V}, f = 1\text{MHz}$		10		pF
Transition frequency	$f_T$	$V_{CE} = 5\text{V}, I_C = 10\text{mA}, f = 100\text{MHz}$	100			MHz

### CLASSIFICATION OF $h_{FE(1)}$

Rank	BC817-16	BC817-25	BC817-40
Range	100-250	160-400	250-600
Marking	6A	6B	6C

TYPICAL CHARACTERISTICS

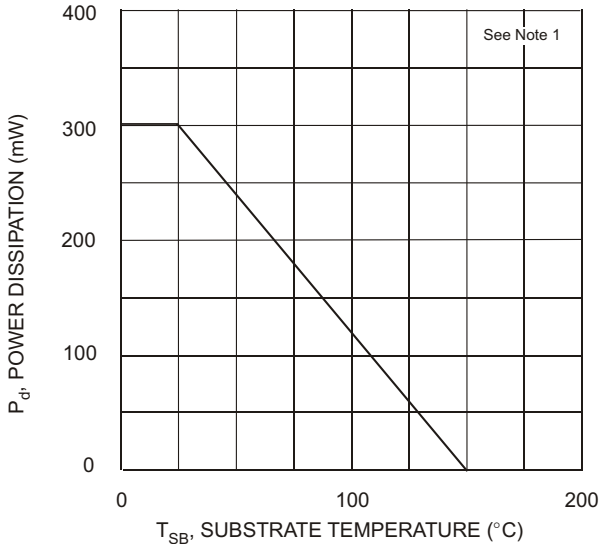


Fig. 1, Power Derating Curve

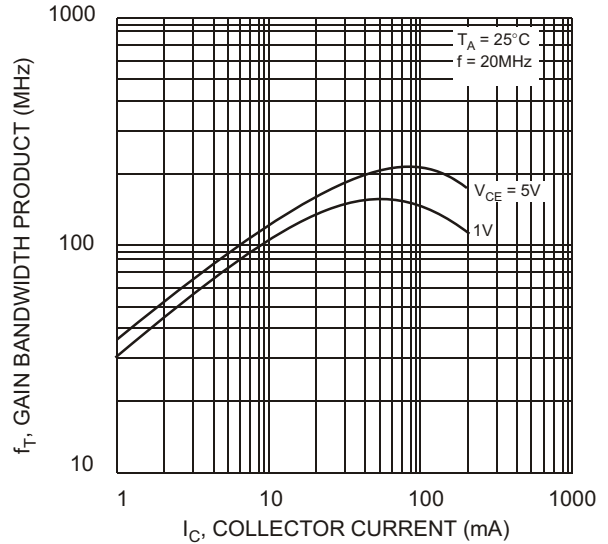


Fig. 2, Gain-Bandwidth Product vs. Collector Current

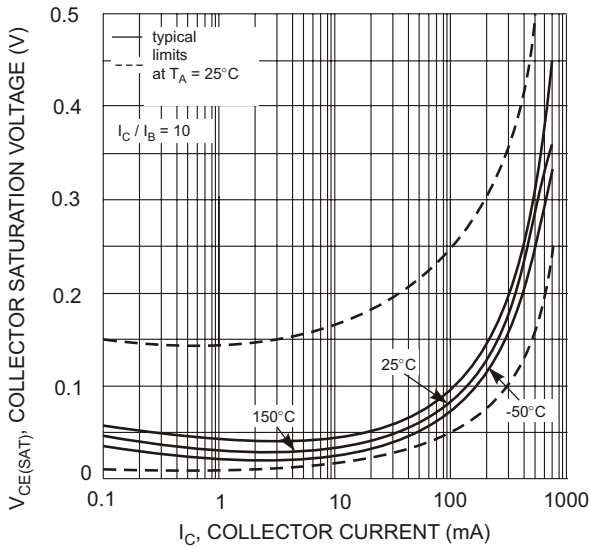


Fig. 3, Collector Sat. Voltage vs. Collector Current

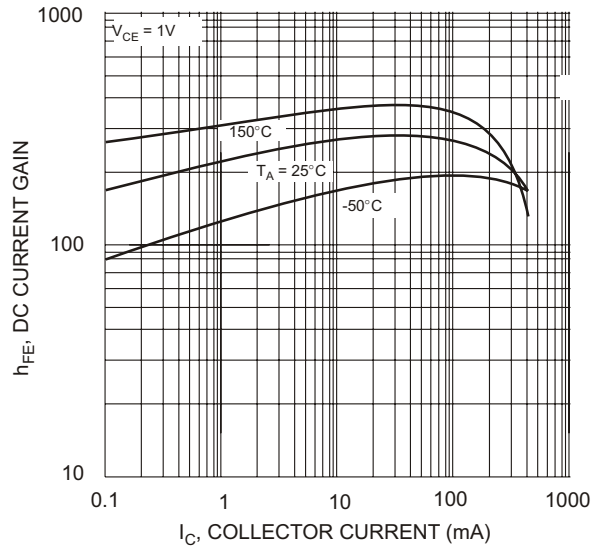


Fig. 4, DC Current Gain vs. Collector Current

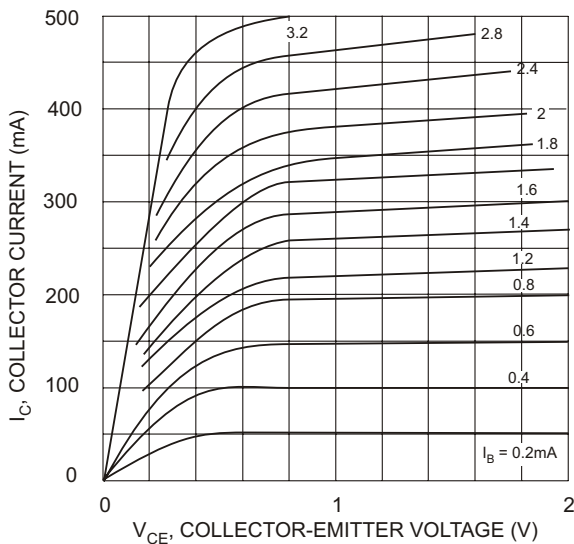


Fig. 5, Typical Emitter-Collector Characteristics

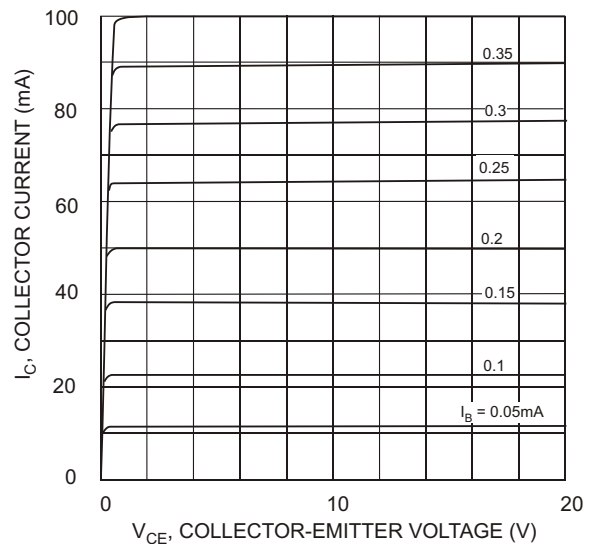
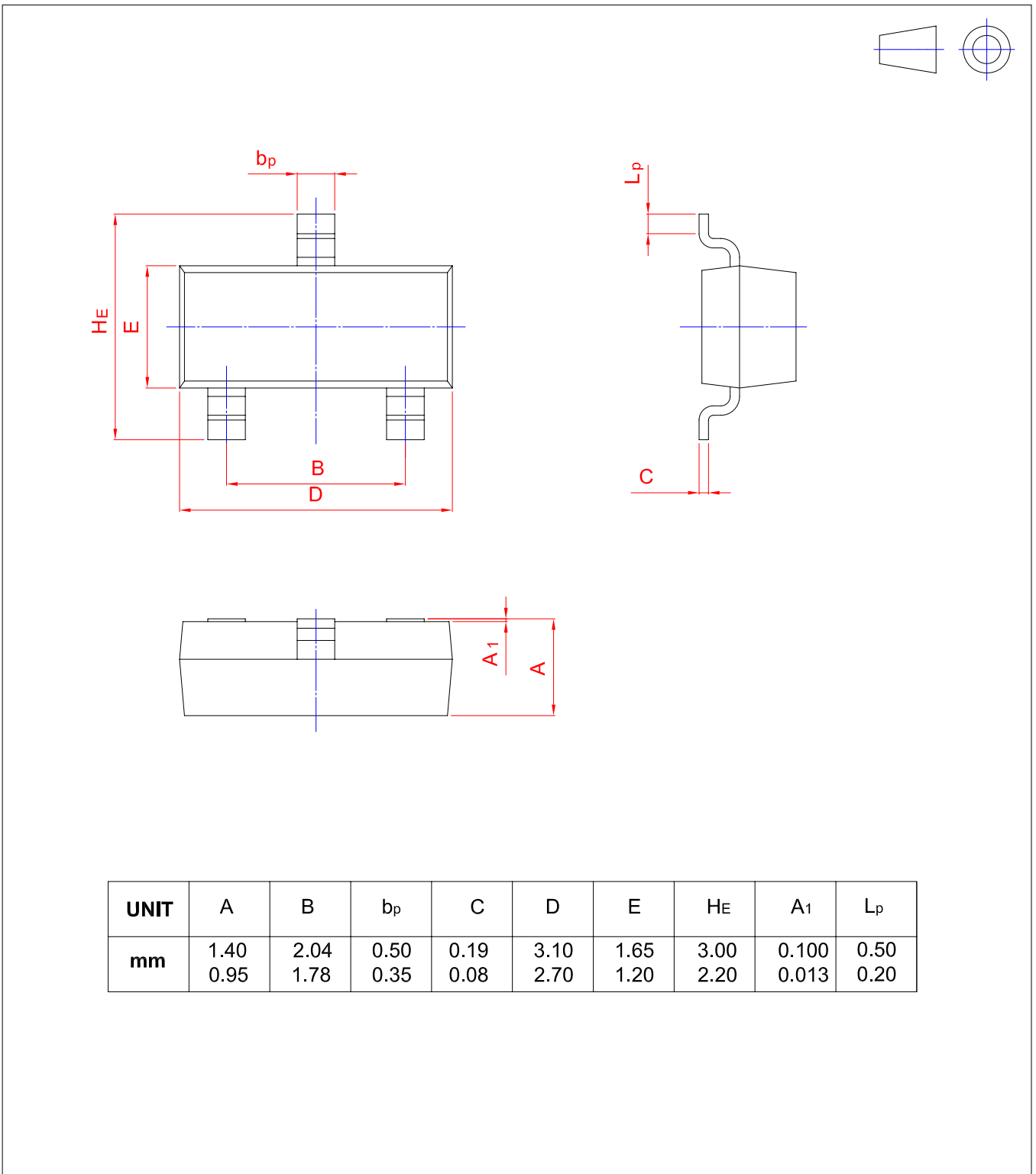


Fig. 6, Typical Emitter-Collector Characteristics

**PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT-23



单击下面可查看定价，库存，交付和生命周期等信息

[>>TWGMC\(台湾迪嘉\)](#)